

HUF75829D3

HUF75829D3 Information



Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



HUF75829D3 Specifications

Manufacturer Part Number	HUF75829D3
Manufacturer	Fairchild/ON Semiconductor
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-251-3 Short Leads, IPak, TO-251AA
Series	UltraFET?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	150V
Current - Continuous Drain (Id) @ 25°C	18A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	10V
Vgs(th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	70nC @ 20V
Input Capacitance (Ciss) (Max) @ Vds	1080pF @ 25V
Vgs (Max)	$\pm 20 V$
FET Feature	-
Power Dissipation (Max)	110W (Tc)
Rds On (Max) @ Id, Vgs	110 mOhm @ 18A, 10V
Operating Temperature	-55°C ~ 175°C (TJ)
Mounting Type	Through Hole
Supplier Device Package	TO-251AA
Package / Case	TO-251-3 Short Leads, IPak, TO-251AA
	Report errors?

HUF75829D3 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE SUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

HUF75829D3 Payment Methods



HUF75829D3 Shipping Methods



If you have any question about HUF75829D3, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com